

MOSFET – Power, Single N-Channel 100 V, 26 mΩ, 28 A

NVMFS027N10MCL

Features

- Small Footprint (5x6 mm) for Compact Design
- Low R_{DS(on)} to Minimize Conduction Losses
- Low Q_G and Capacitance to Minimize Driver Losses
- AEC-Q101 Qualified and PPAP Capable
- NVMFWS027N10MCL Wettable Flank Products
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

Parameter			Symbol	Value	Unit
Drain-to-Source Voltage			V_{DSS}	100	٧
Gate-to-Source Voltage	Gate-to-Source Voltage			±20	V
Continuous Drain		T _C = 25°C	I _D	28	Α
Current R _{θJC} (Notes 1, 3)	Steady	T _C = 100°C		20	
Power Dissipation	State	T _C = 25°C	P_{D}	46	W
R _{θJC} (Note 1)		T _C = 100°C		23	
Continuous Drain		T _A = 25°C	I _D	7.9	Α
Current R _{θJA} (Notes 1, 2, 3)	Steady	T _A = 100°C		5.6	
Power Dissipation	State	T _A = 25°C	P_{D}	3.5	W
R _{θJA} (Notes 1, 2)		T _A = 100°C		1.8	
Pulsed Drain Current	$T_A = 25$	°C, t _p = 10 μs	I _{DM}	137	Α
Operating Junction and Storage Temperature Range			T _J , T _{stg}	-55 to +175	°C
Source Current (Body Diode)			IS	35	Α
Single Pulse Drain-to-Source Avalanche Energy (I _{L(pk)} = 1.3 A)			E _{AS}	414	mJ
Lead Temperature for Soldering Purposes (1/8" from case for 10 s)			TL	260	°C

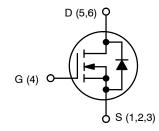
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL RESISTANCE MAXIMUM RATINGS

Parameter	Symbol	Value	Unit
Junction-to-Case - Steady State (Note 1)	$R_{\theta JC}$	3.3	°C/W
Junction-to-Ambient - Steady State (Note 2)	$R_{\theta JA}$	42.4	

- The entire application environment impacts the thermal resistance values shown, they are not constants and are only valid for the particular conditions noted.
- 2. Surface-mounted on FR4 board using a 650 mm², 2 oz. Cu pad.
- Maximum current for pulses as long as 1 second is higher but is dependent on pulse duration and duty cycle.

V _{(BR)DSS}	R _{DS(ON)} MAX	I _D MAX
100 V	26 mΩ @ 10 V	28 A
100 V	35 mΩ @ 4.5 V	2011



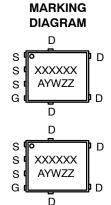
N-CHANNEL MOSFET



DFN5 CASE 488AA STYLE 1



DFNW5 (for WF Version) CASE 507BA



XXXXXX = Specific Device Code A = Assembly Location

Y = Year
W = Work Week
ZZ = Lot Traceability

ORDERING INFORMATION

See detailed ordering, marking and shipping information on page 5 of this data sheet.

ELECTRICAL CHARACTERISTICS ($T_J = 25^{\circ}C$ unless otherwise specified)

Parameter	Symbol	Test Condition		Min	Тур	Max	Unit
OFF CHARACTERISTICS							
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$		100			V
Drain-to-Source Breakdown Voltage Temperature Coefficient	V _{(BR)DSS} /				53		mV/°C
Zero Gate Voltage Drain Current	I _{DSS}	V _{GS} = 0 V,	T _J = 25 °C			1.0	μΑ
		V _{DS} = 100 V	T _J = 125°C			100	
Gate-to-Source Leakage Current	I _{GSS}	V _{DS} = 0 V, V _{GS} = 20 V				100	nA
ON CHARACTERISTICS							
Gate Threshold Voltage	V _{GS(TH)}	$V_{GS} = V_{DS}, I_{D} = 38 \mu A$		1		3	V
Threshold Temperature Coefficient	V _{GS(TH)} /T _J				-6		mV/°C
Drain-to-Source On Resistance	R _{DS(on)}	V _{GS} = 10 V	I _D = 7 A		21	26	
		V _{GS} = 4.5 V	I _D = 5 A		28	35	mΩ
Forward Transconductance	9 _{FS}	V _{DS} = 10 V,	_D = 7 A		25		S
CHARGES, CAPACITANCES & GATE RI	ESISTANCE						
Input Capacitance	C _{ISS}	V _{GS} = 0 V, f = 1 MHz, V _{DS} = 50 V			800		pF
Output Capacitance	C _{OSS}				300		
Reverse Transfer Capacitance	C _{RSS}				4		
Gate Resistance	R_{G}				0.41		Ω
Total Gate Charge	Q _{G(TOT)}	$V_{GS} = 4.5 \text{ V}, V_{DS} = 50 \text{ V}; I_D = 7 \text{ A}$			5.5		nC
Total Gate Charge	Q _{G(TOT)}	V _{GS} = 10 V, V _{DS} = 50 V; I _D = 7 A			11.5		nC
Threshold Gate Charge	Q _{G(TH)}	V _{GS} = 10 V, V _{DS} = 50 V; I _D = 7 A			1.3		
Gate-to-Source Charge	Q _{GS}				2.1		nC
Gate-to-Drain Charge	Q_{GD}				1.2		
Plateau Voltage	V_{GP}				2.5		V
Output Charge	Q _{OSS}	V _{GS} = 0 V, V _{DS} = 50 V			87		nC
SWITCHING CHARACTERISTICS (Note	4)						
Turn-On Delay Time	t _{d(ON)}				7.4		
Rise Time	t _r	V_{GS} = 10 V, V_{DS} = 50 V, I_{D} = 7 A, R_{G} = 6.0 Ω			2		ns
Turn-Off Delay Time	t _{d(OFF)}				19		
Fall Time	t _f				2.9		
DRAIN-SOURCE DIODE CHARACTERIS	STICS						
Forward Diode Voltage	V _{SD}	$V_{GS} = 0 \text{ V, } I_S = 7 \text{ A, } T_J = 25^{\circ}\text{C}$ $V_{GS} = 0 \text{ V, } I_S = 7 \text{ A, } T_J = 125^{\circ}\text{C}$			0.84	1.3	V
					0.73		
Reverse Recovery Time	t _{RR}	V _{GS} = 0 V, dI _S /dt = 100 A/μs, I _S = 3 A			28		ns
Reverse Recovery Charge	Q_{RR}				17		nC
Charge Time	t _a				13.9		ns
Discharge Time	t _b				14.2		ns

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

4. Switching characteristics are independent of operating junction temperatures.

TYPICAL CHARACTERISTICS

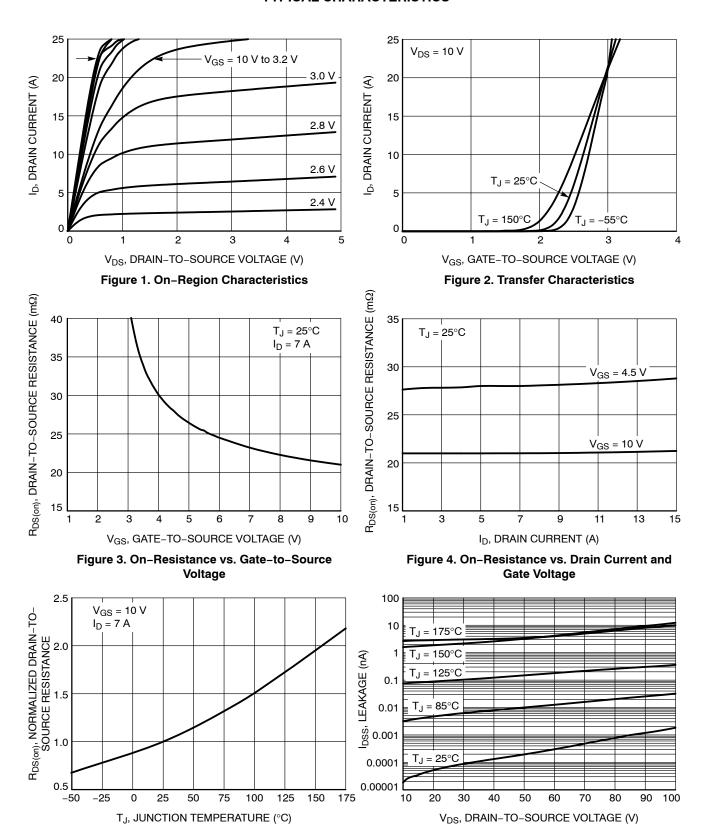


Figure 6. Drain-to-Source Leakage Current

vs. Voltage

Figure 5. On-Resistance Variation with

Temperature

TYPICAL CHARACTERISTICS

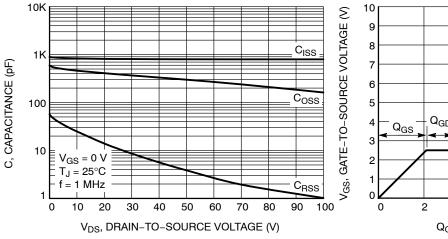


Figure 7. Capacitance Variation

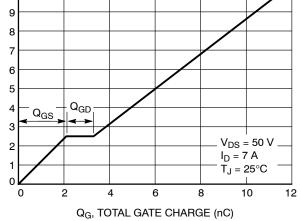
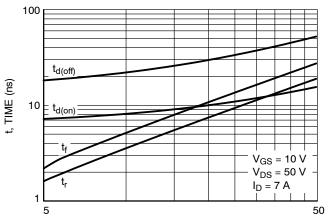


Figure 8. Gate-to-Source and Drain-to-Source Voltage vs. Total Charge



 R_G , GATE RESISTANCE (Ω)

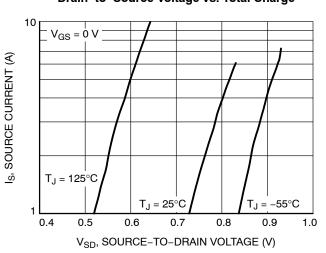


Figure 10. Diode Forward Voltage vs. Current



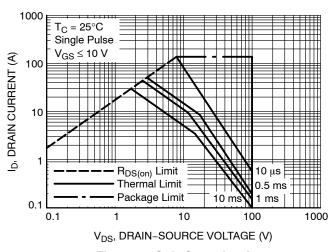


Figure 11. Safe Operating Area

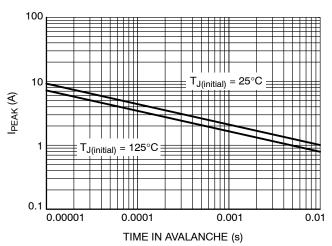


Figure 12. Maximum Drain Current vs. Time in Avalanche

TYPICAL CHARACTERISTICS

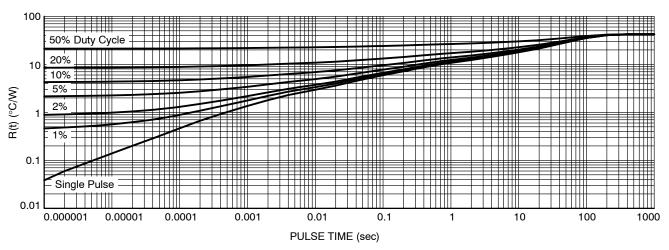


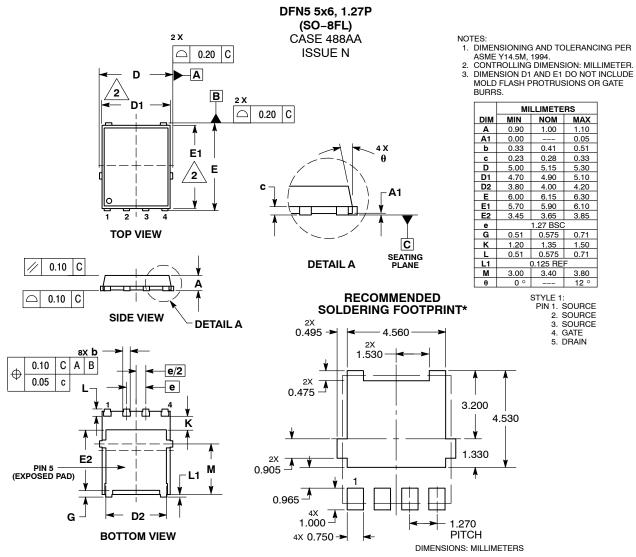
Figure 13. Thermal Response

DEVICE ORDERING INFORMATION

Device	Marking	Package	Shipping [†]
NVMFS027N10MCLT1G	027L10	DFN5 (Pb-Free)	1500 / Tape & Reel
NVMFWS027N10MCLT1G	027W10	DFN5 (Wettable Flank, Pb–Free)	1500 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

PACKAGE DIMENSIONS



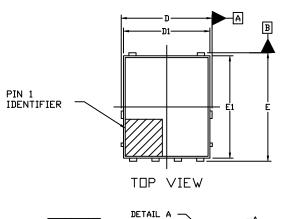
*For additional information on our Pb–Free strategy and soldering details, please download the **onsemi** Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE DIMENSIONS

DFNW5 5x6 (FULL-CUT SO8FL WF)

CASE 507BA **ISSUE A**

SEATING PLANE



SIDE VIEW

// 0.10 C

0.10 C



DIM

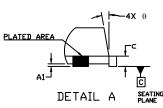
NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2009.
2. CONTROLLING DIMENSION: MILLIMETERS
3. DIMENSIONS D1 AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.
4. THIS PACKAGE CONTAINS WETTABLE FLANK DESIGN FEATURES TO AID IN FILLET FORMATION ON THE LEADS DURING MOUNTING.

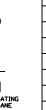
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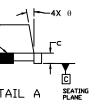
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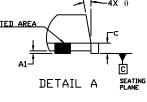
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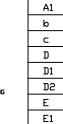
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E2

e

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1.27 BSC

MILLIMETERS

N□M.

1.00

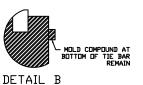
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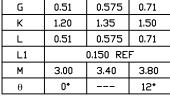
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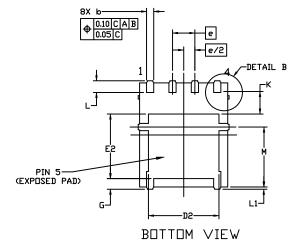
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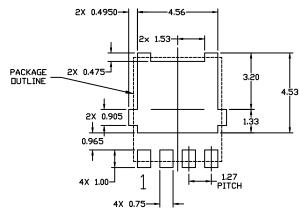
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0.51









RECOMMENDED MOUNTING FOOTPRINT

For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.

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